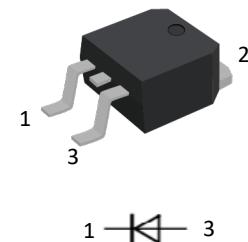


# **4A, 650V SIC Schottky Rectifier**

## **FEATURES**

- 650V schottky rectifier
- Zero reverse recovery current
- Zero forward recovery voltage
- Switching characteristics independent on temperature
- Positive temperature coefficient of forward voltage
- High temperature soldering guaranteed: 260°C/10 seconds
- RoHS compliant
- Halogen free

**TO-263AB**



**RoHS**  
COMPLIANT

**HALOGEN**  
FREE

## **MECHANICAL DATA**

- Case: TO-263AB
- Case material: molding compound meets UL 94V-0 flammability rating
- Polarity: as marked on case

## **TYPICAL APPLICATION**

General purpose use in HAVC,SMPS, AC/DC converters,free wheeling diodes in inverter stages.

## **MAXIMUM RATINGS**

$T_J=25^\circ\text{C}$  unless otherwise noted

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	650	V
Average Forward Rectified Current ( $T_C=150^\circ\text{C}$ )	$I_F$	4	A
Repetitive Peak Forward Surge Current ( $t_p=10\text{ms}, T_C=25^\circ\text{C}$ )	$I_{FRM}$	20	A
Peak Forward Surge Current ( $t_p=10\text{ms}, T_C=25^\circ\text{C}$ )	$I_{FSM}$	26	A
Non-Repetitive peak forward surge current ( $t_p = 10 \mu\text{s}; T_C = 25^\circ\text{C}$ , pulse)	$I_{Fmax}$	200	A
Power Dissipation $T_C=25^\circ\text{C}$ $T_C=110^\circ\text{C}$	$P_{tot}$	76.5 33.2	W
Operating Junction Temperature Range	$T_J$	-55 to +175	°C
Storage Temperature Range	$T_{STG}$	-55 to +175	°C

# 4A, 650V SIC Schottky Rectifier

## ELECTRICAL CHARACTERISTICS

$T_J=25^\circ\text{C}$  unless otherwise noted

Parameter	Test Conditions	Symbol	Value		Unit
			Typ.	Max.	
Forward Voltage@ $I_F=4\text{A}$	$T_J=25^\circ\text{C}$	$V_F$	1.5	1.8	V
	$T_J=175^\circ\text{C}$		1.8	2	
Reverse Current @ $V_{RRM}$	$T_J=25^\circ\text{C}$	$I_R$	1	20	$\mu\text{A}$
	$T_J=175^\circ\text{C}$		12	100	
Total Capacitance	$V_R=0\text{V}, f=1\text{MHz}$	C	185	-	$\text{pF}$
	$V_R=200\text{V}, f=1\text{MHz}$		19	-	
	$V_R=400\text{V}, f=1\text{MHz}$		16.7	-	
Total Capacitance Charge	$V_R=400\text{V}$	$Q_C$	9.5	-	nC
Capacitance Stored Energy	$V_R=400\text{V}$	$E_C$	2.4	-	$\mu\text{J}$
Thermal Resistance		$R_{\theta JC}$	1.5		$^\circ\text{C}/\text{W}$

## RATINGS AND CHARACTERISTIC CURVES

FIG.1: Forward characteristics

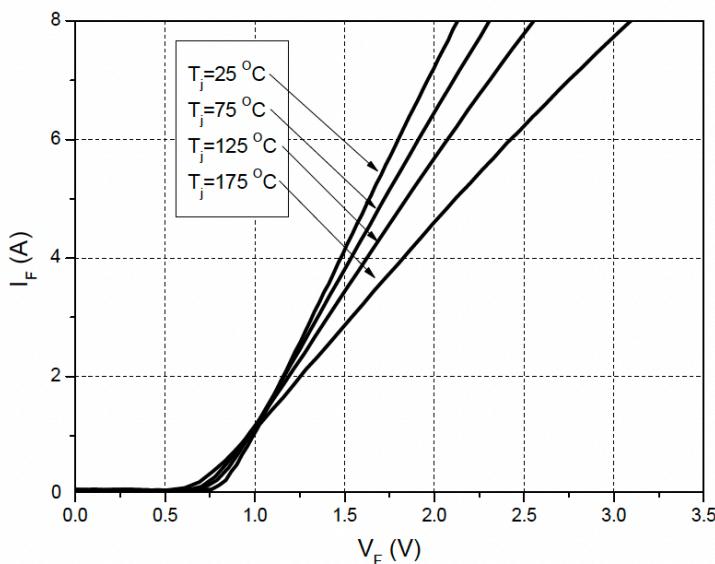
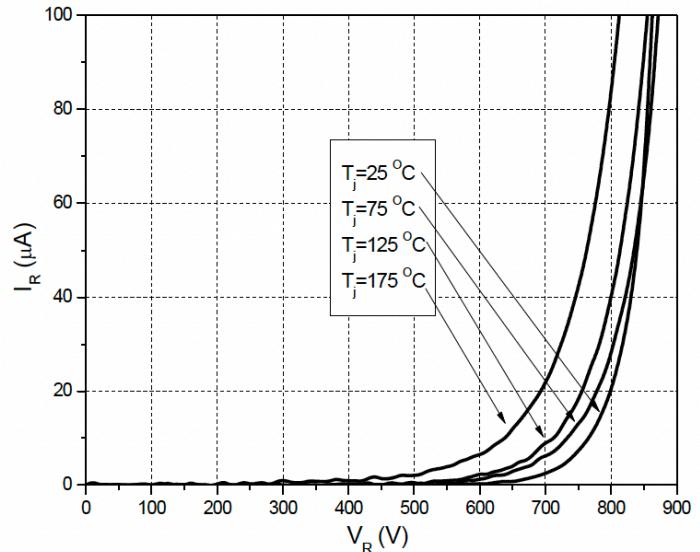


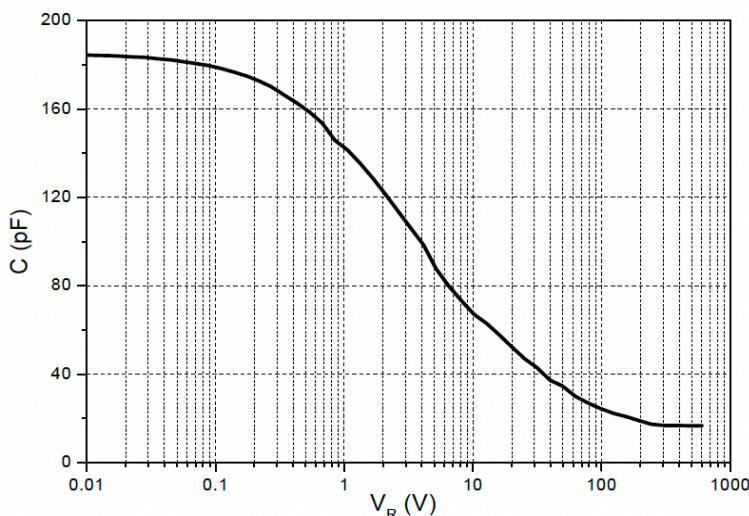
FIG.2: Reverse characteristics



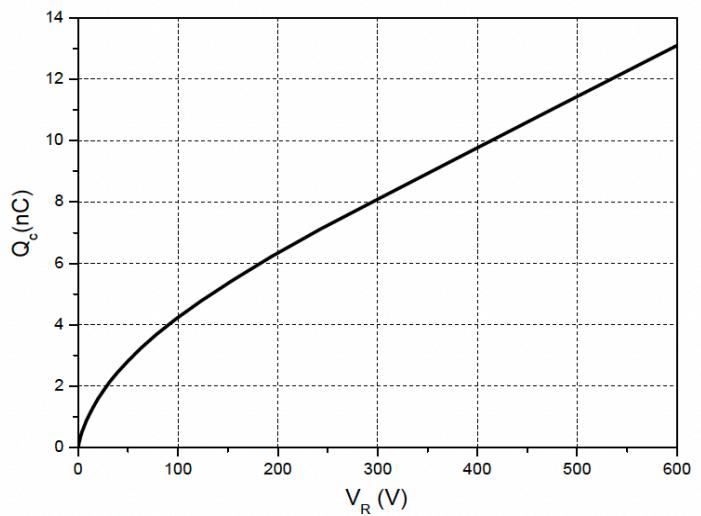
# **4A, 650V SiC Schottky Rectifier**

## RATINGS AND CHARACTERISTIC CURVES

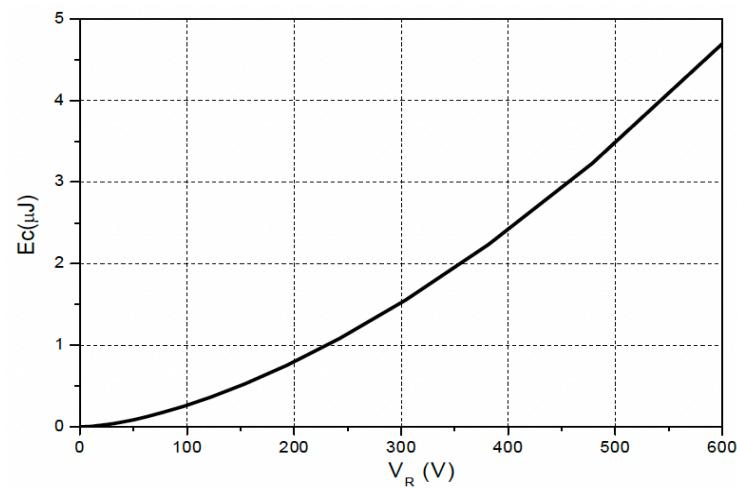
**FIG.3: Capacitance vs. reverse voltage**



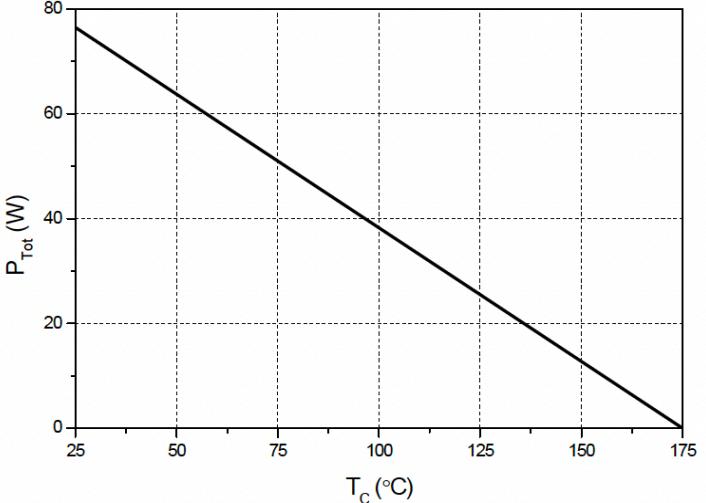
**FIG.4: Reverse characteristics**



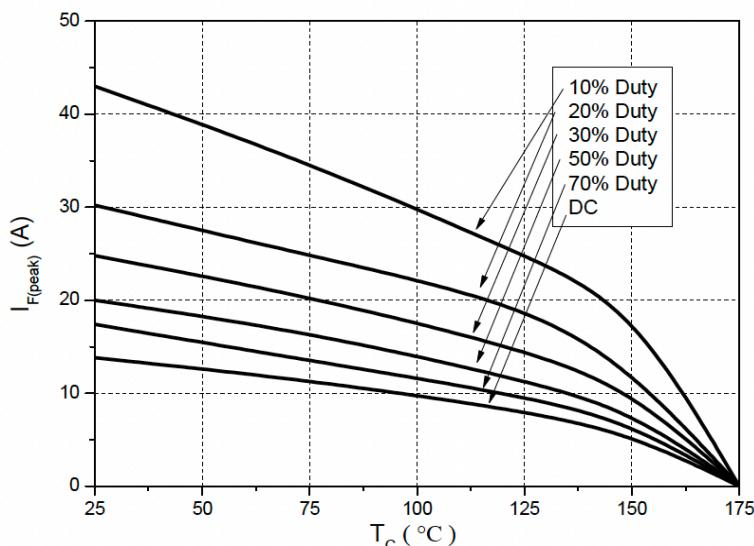
**FIG.5: Capacitance stored energy**



**FIG.6: Power derating**

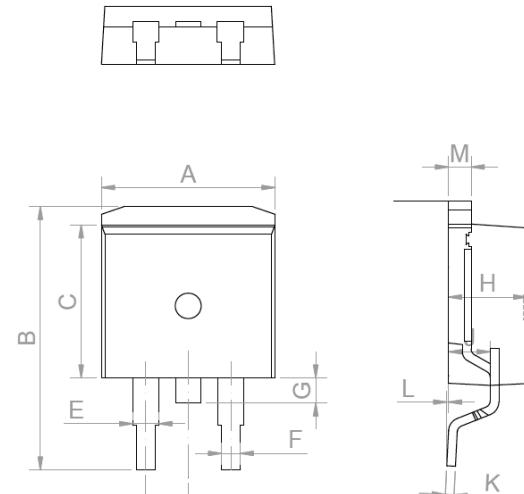


**FIG.7: Current derating**



# **4A, 650V SIC Schottky Rectifier**

## **PACKAGE OUTLINE DIMENSIONS**



TO-263

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	8.80		9.60	0.346		0.378
D		2.54			0.100	
E	1.20		1.40	0.047		0.055
F	0.75		0.85	0.030		0.033
G			1.75			0.069
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
M	1.17		1.37	0.046		0.054

## **PACKING INFORMATION**

Package	Tube(PCS)	Inner Box(PCS)	Carton(PCS)
TO-263AB	50	1,000	5,000